BLA9H0912L-1200P; BLA9H0912LS-1200P(G) LDMOS avionics power transistor Rev. 2 — 10 January 2023 P

AMMPLEON

Product data sheet

Product profile

1.1 General description

1200 W LDMOS power transistor for avionics applications in the frequency range of 960 MHz to 1215 MHz.

Typical performance Table 1.

Typical RF performance at T_{case} = 25 °C; t_{D} = 50 μ s; δ = 2 %; I_{Dq} = 75 mA; in a class-AB demo circuit.

Test signal	f	V _{DS}	PL	Gp	ησ
	(MHz)	(V)	(W)	(dB)	(%)
pulsed RF	1030	50	1200	19	60
pulsed RF at 1 dB compression	960 to 1215	50	>1050	19	57

1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for avionics band operation
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

Avionics applications in the frequency range of 960 MHz to 1215 MHz

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLA9H0912L	-1200P (SOT539A)		
1	drain1		
2	drain2	1 2	1
3	gate1	5	
4	gate2	3 4	5
5	source [1]		4
BLA9H0912L	S-1200P (SOT539B)		sym117
1	drain1		
2	drain2	1 2	1 .∟
3	gate1	5	
4	gate2	3 4	5
5	source [1]		2 sym117
BLA9H0912L	S-1200PG (SOT1248C)		
1	drain1	1 0	1
2	drain2		
3	gate1	5	3 -5
4	gate2	3 4	4 7
5	source [1]		2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	ge			
	Name				
BLA9H0912L-1200P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A		
BLA9H0912LS-1200P	-	earless flanged balanced ceramic package; 4 leads	SOT539B		
BLA9H0912LS-1200PG	-	earless flanged LDMOST ceramic package; 4 leads	SOT1248C		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	106	V
V_{GS}	gate-source voltage	-6	+11	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{th(j-mb)}$	transient thermal impedance from junction	T _{case} = 85 °C; P _L = 1200 W		
	to mounting base	$t_p = 32 \ \mu s; \ \delta = 2 \ \%$	0.027	K/W
		$t_p = 10 \ \mu s; \ \delta = 10 \ \%$	0.036	K/W
		$t_p = 64 \ \mu s; \ \delta = 1 \ \%$	0.032	K/W
		t_p = 2.4 ms; δ = 6.4 %	0.126	K/W

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C, per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 4 \text{ mA}$	106	-	-	٧
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 400 \text{ mA}$	1.5	2.0	2.5	٧
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	60	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 400 \text{ mA}$	-	3.7	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 14 \text{ A}$	-	0.060	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF; f = 1030 MHz; t_p = 50 μ s; δ = 2 %; RF performance at V_{DS} = 50 V; I_{Dq} = 75 mA; T_{case} = 25 $^{\circ}$ C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 1200 W	17.8	19	-	dB
η_{D}	drain efficiency	P _L = 1200 W	57	60	-	%
RLin	input return loss	P _L = 1200 W	-	-15	-	dB
P _{droop(pulse)}	pulse droop power	P _L = 1200 W	-	0.2	0.5	dB

Table 7. RF characteristics ... continued

Test signal: pulsed RF; f = 1030 MHz; t_p = 50 μ s; δ = 2 %; RF performance at V_{DS} = 50 V; I_{Dq} = 75 mA; T_{case} = 25 $^{\circ}$ C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _r	rise time	P _L = 1200 W	-	6	50	ns
t _f	fall time	P _L = 1200 W	-	6	50	ns
P _{L(2dB)}	output power at 2 dB gain compression		-	1400	-	W

7. Test information

7.1 Ruggedness in class-AB operation

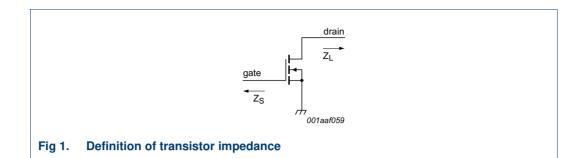
The BLA9H0912L-1200P, BLA9H0912LS-1200P and BLA9H0912LS-1200PG are capable of withstanding a load mismatch corresponding to VSWR = 20 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 75 mA; P_{L} = 1200 W; t_{p} = 50 μ s; δ = 2 %.

7.2 Impedance information

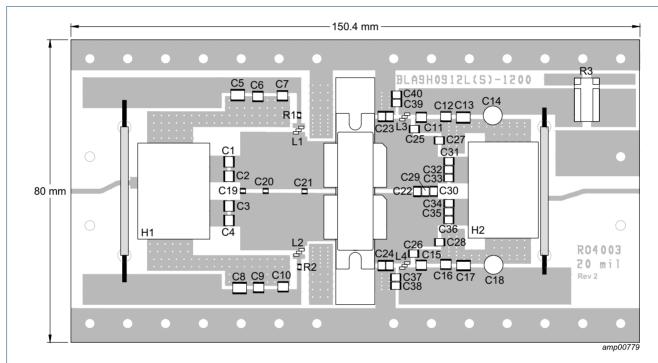
Table 8. Typical impedance (per section)

f	Z _S [1]	Z _L [1]				
(MHz)	(Ω)	(Ω)				
BLA9H0912L-1200P; BLA9H09	BLA9H0912L-1200P; BLA9H0912LS-1200P					
950	0.717 – j1.793	0.965 – j1.305				
1000	0.953 – j1.886	1.049 – j1.561				
1050	1.091 – j1.910	1.032 – j1.780				
1100	1.353 – j0.443	1.291 – j1.952				
1150	1.962 – j1.061	1.474 – j2.081				
1200	0.837 – j0.936	1.514 – j2.413				
BLA9H0912LS-1200PG						
950	0.864 – j4.192	1.114 – j3.604				
1000	1.168 – j4.414	1.249 – j4.020				
1050	1.354 – j4.560	1.267 – j4.411				
1100	1.481 – j2.963	1.625 – j4.718				
1150	2.274 – j3.655	1.901 – j4.980				
1200	1.097 – j3.801	2.087 – j5.532				

^[1] Z_S and Z_L defined in Figure 1.



7.3 Test circuit



Printed-Circuit Board (PCB): RO4003; ϵ_r = 3.55; thickness = 0.508 mm; thickness copper plating = 35 μ m. See Table 9 for a list of components.

Fig 2. Component layout for application circuit

Table 9. List of components
See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C2, C3, C4	multilayer ceramic chip capacitor	39 pF	ATC 100B
C5, C8, C13, C17	multilayer ceramic chip capacitor	10 μF	Murata: GRM55DR61H106KA88L
C6, C9, C12, C16	multilayer ceramic chip capacitor	1 nF	ATC 100B
C7, C10, C11, C15	multilayer ceramic chip capacitor	51 pF	ATC 100B
C14, C18	electrolytic capacitor	100 μF, 63 V	
C19, C20	multilayer ceramic chip capacitor	0.5 pF	ATC 100A
C21	multilayer ceramic chip capacitor	5.6 pF	ATC 100A
C22	multilayer ceramic chip capacitor	3.0 pF	ATC 100B

BLA9H0912L-1200P_LS-1200P_LS-1200PG

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Table 9. List of components ... continued

See Figure 2 for component layout.

Component	Description	Value	Remarks
C23a, C23b, C24a, C24b	multilayer ceramic chip capacitor	5.1 pF	ATC 800B
C25, C26, C27, C28	multilayer ceramic chip capacitor	2.4 pF	ATC 100B
C29	multilayer ceramic chip capacitor	0.8 pF	ATC 100B
C30	multilayer ceramic chip capacitor	1.6 pF	ATC 100B
C31, C32, C33, C34, C35, C36	multilayer ceramic chip capacitor	43 pF	ATC 100B
C37, C39	multilayer ceramic chip capacitor	20 nF	ATC 200B
C38, C40	multilayer ceramic chip capacitor	1 nF	ATC 200B
H1, H2	balun transformer		Anaren: 3A412S
L1, L2	inductor	27 nH	Coilcraft: 1111SQ-27NJEB
L3, L4	inductor	1/2 turns, D = 1.5 mm, 8.9 nH	8 mm copper wire
R1, R2	resistor	5 Ω	SMD 0603
R3	resistor	5 mΩ	FC4L110R005FER

7.4 Graphical data

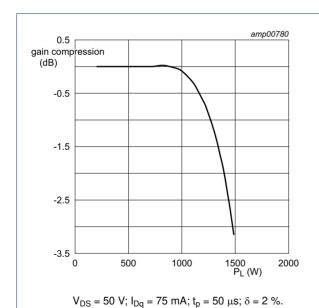
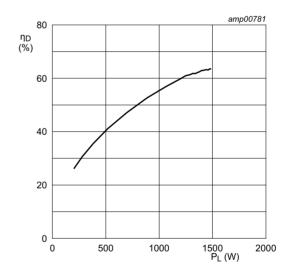


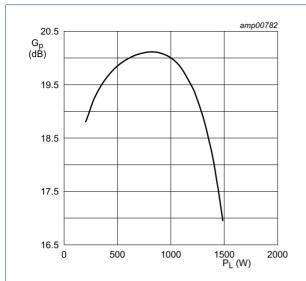
Fig 3. Gain compression as a function of output

power; typical values



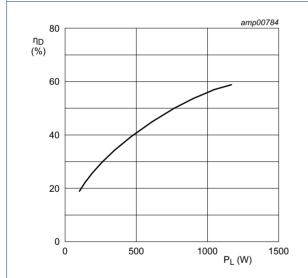
 V_{DS} = 50 V; I_{Dq} = 75 mA; t_p = 50 $\mu s;$ δ = 2 %.

Fig 4. Drain efficiency as a function of output power; typical values



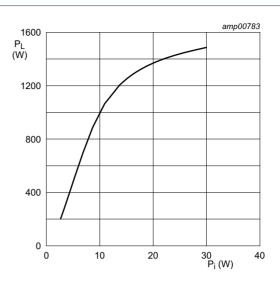
 V_{DS} = 50 V; I_{Dq} = 75 mA; t_p = 50 $\mu s; \, \delta$ = 2 %.

Fig 5. Power gain as a function of output power; typical values



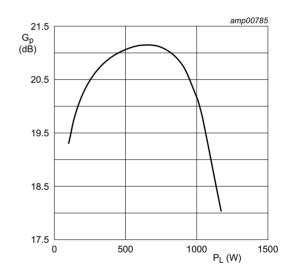
 $V_{DS}=50~V;~I_{Dq}=200~mA;~t_p=2.4~ms;~\delta=6.4~\%.$ Fig 7. Drain efficiency as a function of output power;

typical values



 V_{DS} = 50 V; I_{Dq} = 75 mA; t_p = 50 $\mu s; \, \delta$ = 2 %.

Fig 6. Output power as a function of input power; typical values



 V_{DS} = 50 V; I_{Dq} = 200 mA; t_p = 2.4 ms; δ = 6.4 %.

Fig 8. Power gain as a function of output power; typical values

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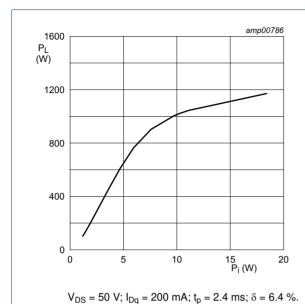
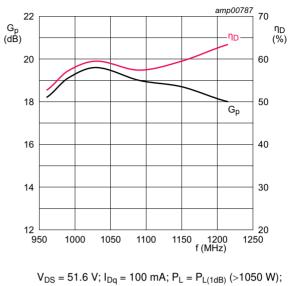


Fig 9. Output power as a function of input power; typical values



 $v_{DS} = 51.6 \text{ V; } I_{Dq} = 100 \text{ mA; } P_L = P_{L(1dB)} (>1050 \text{ W})$ $t_p = 50 \text{ µs; } \delta = 5 \text{ %.}$ Performance measured in a dedicated broadband fixture.

Fig 10. Power gain and drain efficiency as function of frequency; typical values

8. Package outline

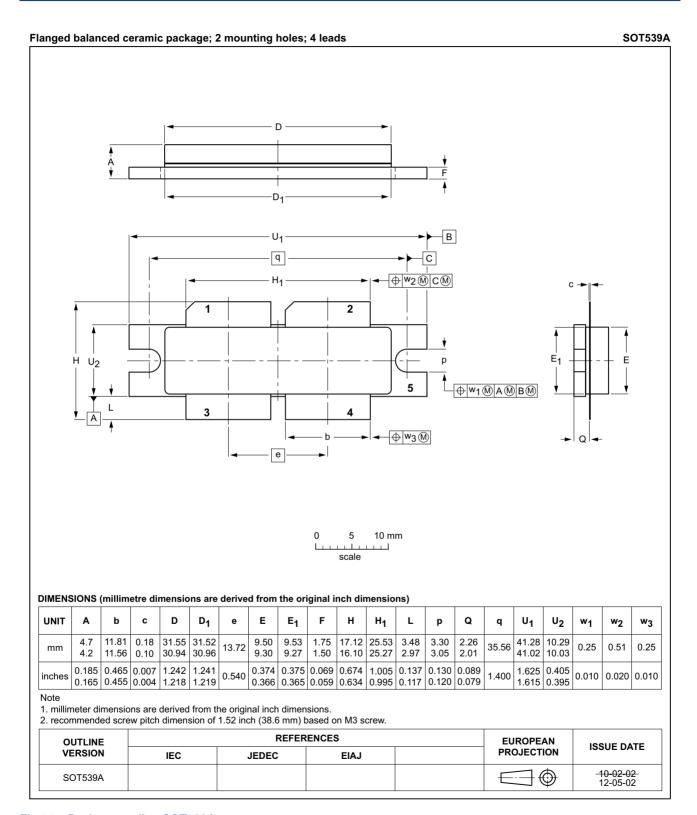


Fig 11. Package outline SOT539A

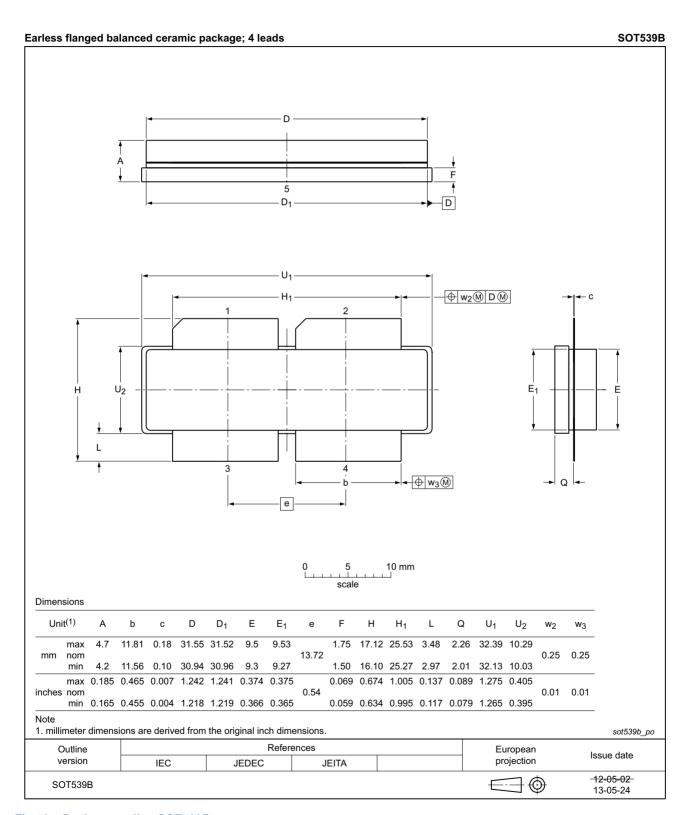


Fig 12. Package outline SOT539B

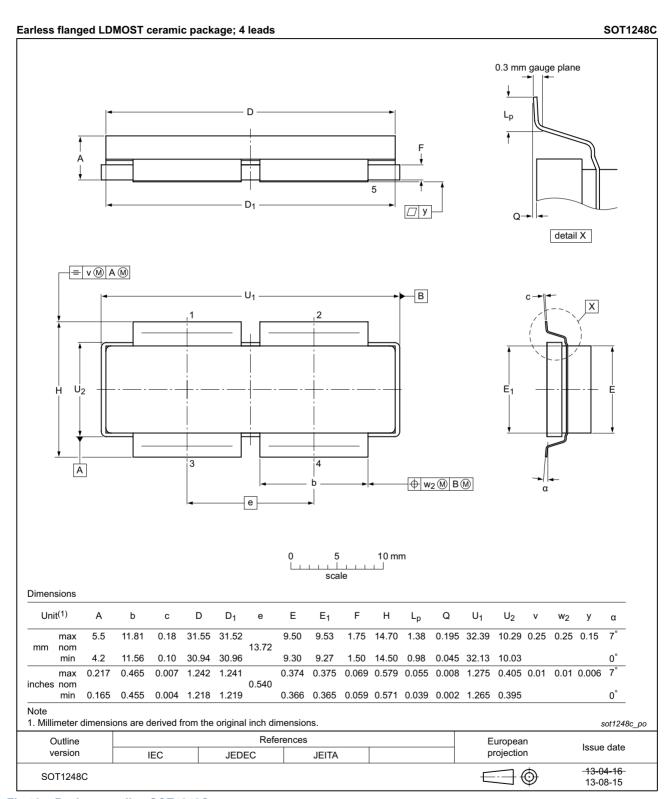


Fig 13. Package outline SOT1248C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
MTF	Median Time to Failure
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLA9H0912L-1200P_LS-1200P_LS- 1200PG v.2	20230110	Product data sheet	-	BLA9H0912L-1200P_LS- 1200P v.1	
Modifications:	<u>Table 2 on page 2</u> : added BLA9H0912LS-1200PG				
	Table 3 on page 2: added BLA9H0912LS-1200PG				
	 <u>Table 5 on page 3</u>: changed P_L value from 600 W to 1200 W 				
	Section 7.1 on page 4: added BLA9H0912LS-1200PG				
	<u>Table 8 on page 4</u> : updated table				
	Figure 13 on page 11: added figure of package outline SOT1248C				
	Section 12.2 on page 13: updated section				
	Section 12.3 on page 13: updated section				
BLA9H0912L-1200P_LS-1200P v.1	20181101	Product data sheet	-	-	

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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